

Description

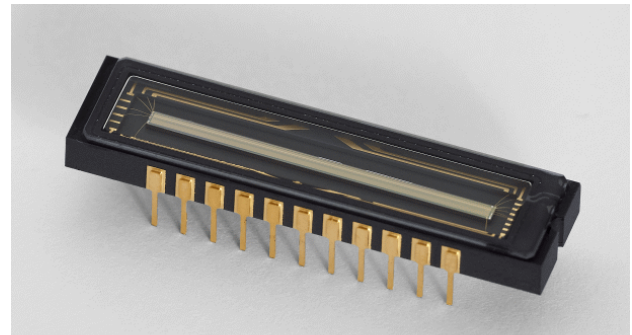
ITR-511 is a high performance CMOS linear image sensor with 2048 pixels. The ITR-511 can be used as a socket-compatible replacement for the Sony ILX511B CCD linear sensor. Advanced CMOS technology is used to emulate the signal level scheme of the ILX511B ensuring both signal level and pin compatibility. In comparison with sensors based on CCD technology, the ITR-511 offers better or equal performance. The ITR-511 requires a single 5V power supply.

Features

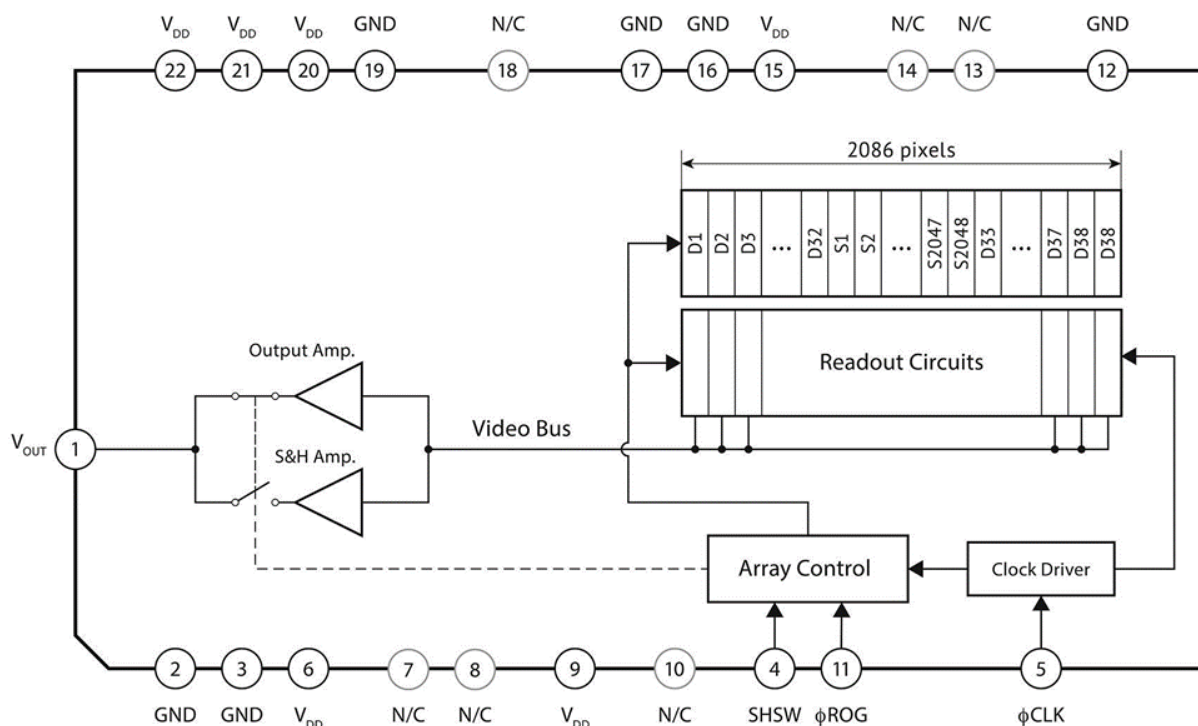
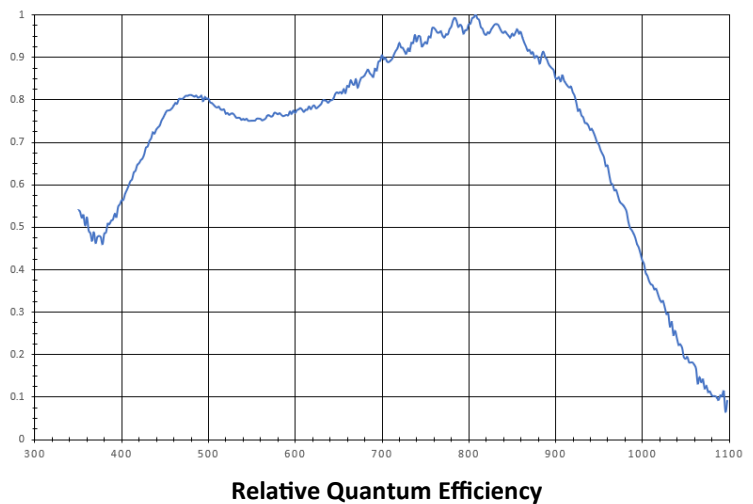
- CMOS image sensor to replace former CCD
- 2048 active pixels aligned as in the former CCD
- 14µm x 196µm pixels for optical compatibility
- Single 5 volt supply - no higher voltages needed
- Emulates signals used with the former CCD
- Output signal compatible with existing readout circuits
- Supports clock rates in excess of 2 MHz
- Available with temporary window for UV applications
- Ceramic package and gold-plated pins
- High red and near-infrared response with low ripple

Pinout Configuration

The pinout on the ITR-511 is identical to that of the ILX511B except that pins used for high-voltage supplies are not connected. This permits use of existing power circuits.



ITR-511-SW



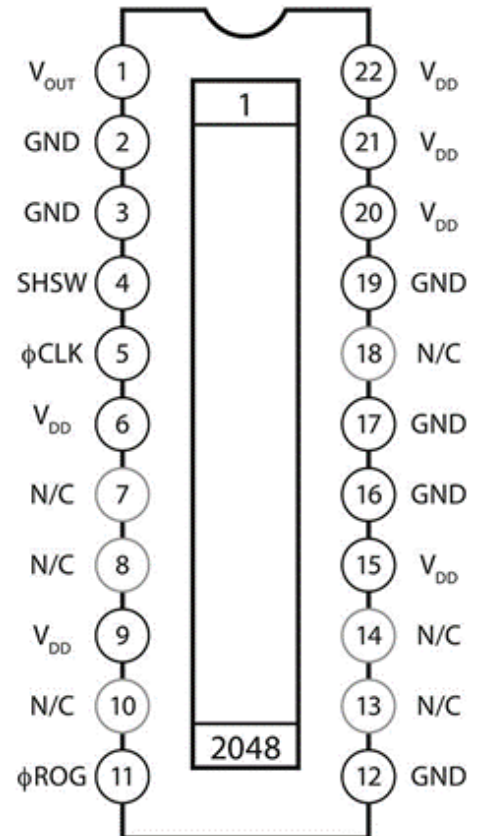
ITR-511 2048-Pixel CMOS Line Sensor

Product Brief

Pinout

The pin layout for the ITR-511 is the same as in the ILX511B except that the ITR-511 requires only a single 5 volt supply. The pin for VGG is left unconnected for socket compatibility.

#	ILX511B	ITR-511	Signal Description
1	VOUT	VOUT	Signal output
2	GND	GND	Ground
3	GND	GND	Ground
4	SHSW	SHSW	S/H switch, ON:gnd, OFF:vdd
5	Φ CLK	Φ CLK	Falling edge Clock
6	VDD	VDD	5V power supply
7	NC	NC	No Connection
8	NC	NC	No Connection
9	VDD	VDD	5V power supply
10	NC	NC	No Connection
11	Φ ROG	Φ ROG	Readout gate input, active Low
12	GND	GND	Ground
13	NC	NC	No Connection
14	NC	NC	No Connection
15	VDD	VDD	5V power supply
16	GND	GND	Ground
17	GND	GND	Ground
18	VGG	NC	No Connection
19	GND	GND	Ground
20	VDD	VDD	5V power supply
21	VDD	VDD	5V power supply
22	VDD	VDD	5V power supply



Absolute Maximum Ratings

The 5 volt supply must not be allowed to exceed 5.5 volts to avoid damage to the device.

Operating temperature: -10 to +60°C

Storage temperature: -30 to +80°C

Sample & Hold Mode Selection

The S/H function keeps the readout level constant during each clock period but delays the output by one clock pulse. See timing diagrams.

Mode	Pin name	Pin number	Note
S/H	SHSW	4	Sample & hold enable signal, ON: GND, OFF: VDD

Operating Conditions

Recommended Power Supply

Item	Min	Typ	Max	Unit	Note
V _{DD}	4.5	5.0	5.5	V	

Recommended Clock Voltages

Item	Min	Typ	Max	Unit	Note
V _{IH}	V _{DD} - 0.5	V _{DD}	V _{DD} + 0.5	V	
V _{IL}	-0.3	0	0.5	V	

Input Pin Capacitance

Item	Min	Typ	Max	Unit	Note
C _{CLK}	-	10	-	pF	
C _{ROG}	-	10	-	pF	

Electro-Optical Characteristics

Signal Summary

Item	Min	Typ	Max	Unit	Note
V _{sat}	1.8	2.0	2.2	V	Output saturation level
V _{os}	-	2.9	-	V	Output offset level
I _{vdd} *	-	20	40	mA	
Readout Noise	-	-	500	uV	
DR	-	4000	-		Dynamic range = V _{sat} /readout noise
Output Impedance	-	160	-	Ω	
Package Temperature	-	-10 to +60	-	°C	

*operating conditions as specified in the timing diagram

Optical summary

	Symbol	Min	Typ	Max	Unit	Note
Sensitivity	R630	-	420	-	V/[uJ/cm ²]	λ = 630nm
Sensitivity nonuniformity	PRNU	-	10	-	%	1.0V Output Voltage
Dark voltage nonuniformity	DSNU	-	30	-	mV	10ms Integration Time

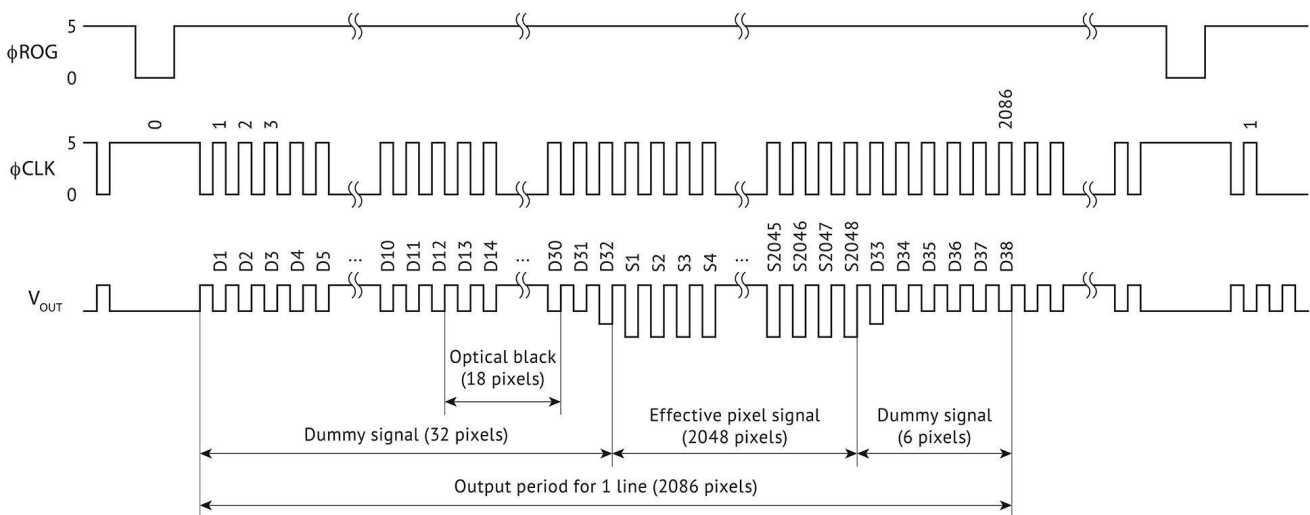
ITR-511 Operation

The ITR-511 consists of a single row of photodiodes connected to two sets of storage and readout registers to permit integration during readout.

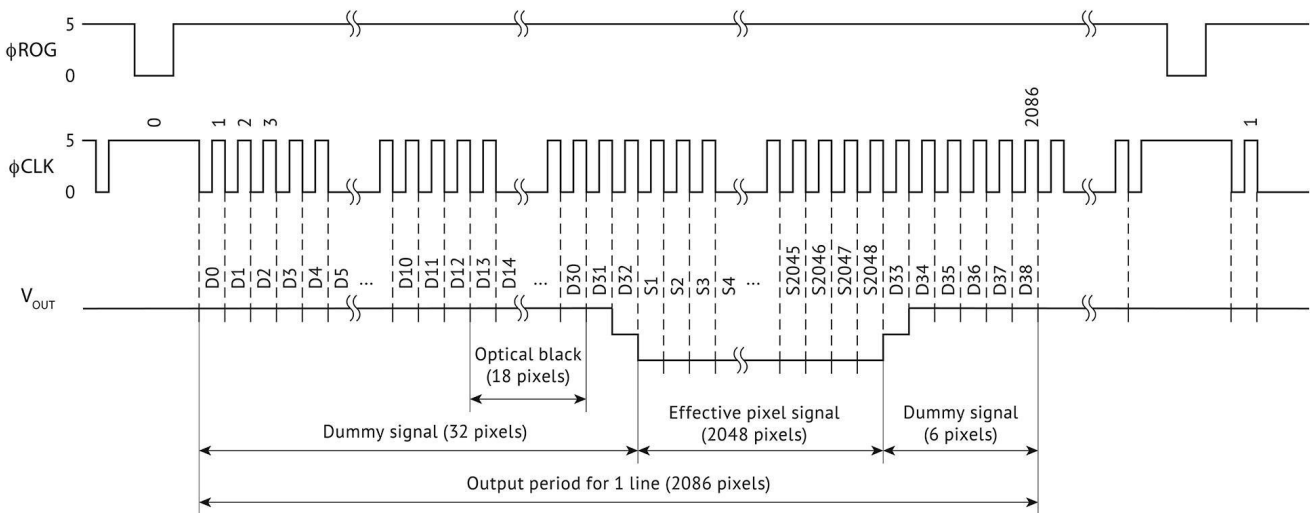
The photodiode row consists of a section of 2048 active photodiodes each 14 x 196 μm in size with 32 dummy photodiodes leading the array and 6 following. 18 optical black pixels (D15 to D32) before and 6 after (D33 to D38) may be used as a dark reference. Systems with wide optical angles at the sensor should avoid using the pixels directly adjacent to the active area for dark reference.

Only two real time signals are required to operate the ITR-511 - ϕ_{ROG} to initiate a readout/integration cycle, and ϕ_{CLK} to read out the pixel data line. A third signal SHSW, allows selection of an internal sample and hold circuit for application circuits which do not provide this function. When the internal S/H is used, the ITR-511 performs a CDS operation on each pixel for noise reduction.

Timing Diagrams



Overall timing at normal mode



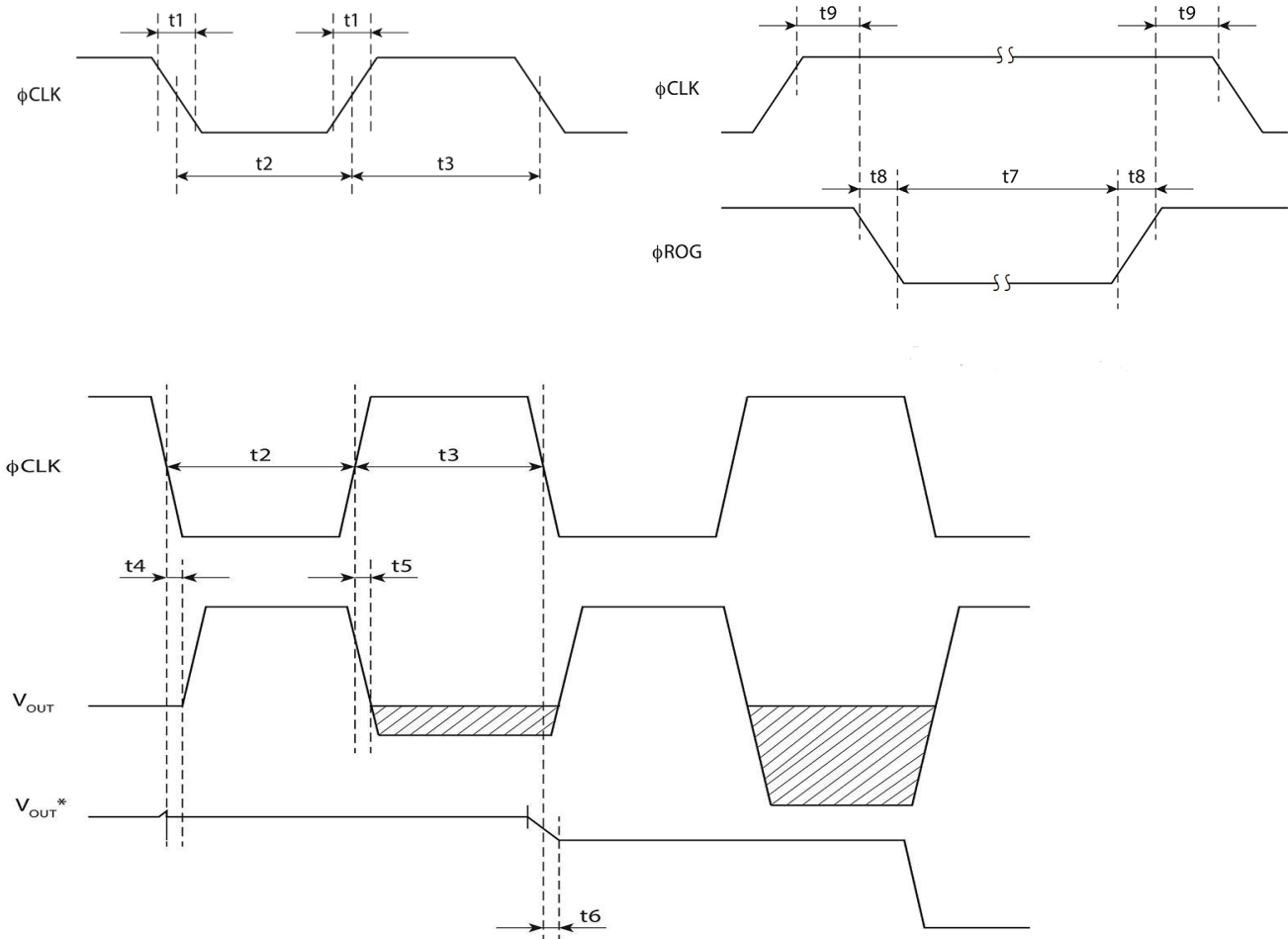
Overall timing at S&H mode

ITR-511 2048-Pixel CMOS Line Sensor

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Clock, ROG and Video Output Timing

The waveforms and tables are below



Item	Symbol	Min	Typ	Max	Unit	Note
Clock frequency		-	2	5	MHz	
CLK pulse duty		40	50	60	%	$=100 \times t3/(t2+t3)^*$
CLK rise/fall time	t1	0	1	20	ns	
CLK pulse width	t2, t3	100	250	-	ns	
ROG pulse period	t7	500	1000	-	ns	
ROG, rise & fall	t8	0	1	20	ns	
CLK - ROG timing	t9	10	1000	-	ns	
CLK - Vout, rise	t4	29	37	45	ns	Delay
CLK - Vout, fall	t5	25	33	41	ns	Delay
CLK - Vout, fall w/ S&H	t6	42	50	58	ns	Delay

* Duty cycles to 75/25 may be tolerated if the clock frequency is 0.5 MHz or below.

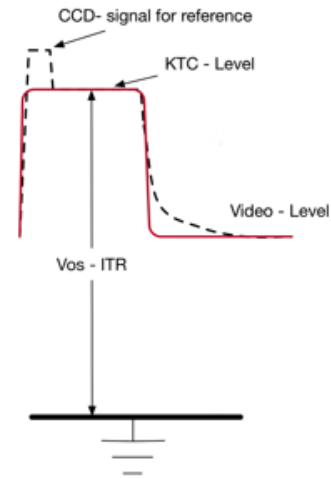
ITR-511 2048-Pixel CMOS Line Sensor

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Video Output

The output signal from the ITR-511 is a negative-going analog voltage. With no exposure, the output is a stable reset (KTC) level positioned at the output offset voltage, V_{os} . The reset pulse feedthrough from the ILX-511B is not present in the ITR series devices and the risetimes are faster in the ITR devices. The ITR output is shown with the CCD output shown as a dotted line for reference. V_{os} may be different in the two devices.

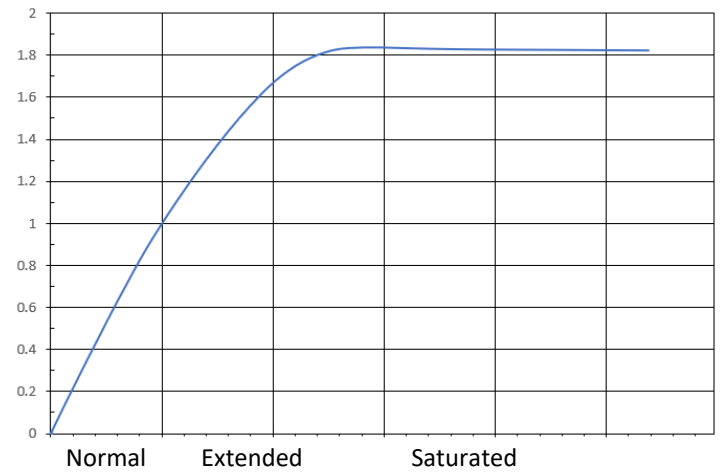
In the ITR-511, the zero signal level after reset may be above the reset level by up to tens of millivolts. The ADC reference should be chosen so that this portion of the signal is not lost.



Signal vs. Exposure

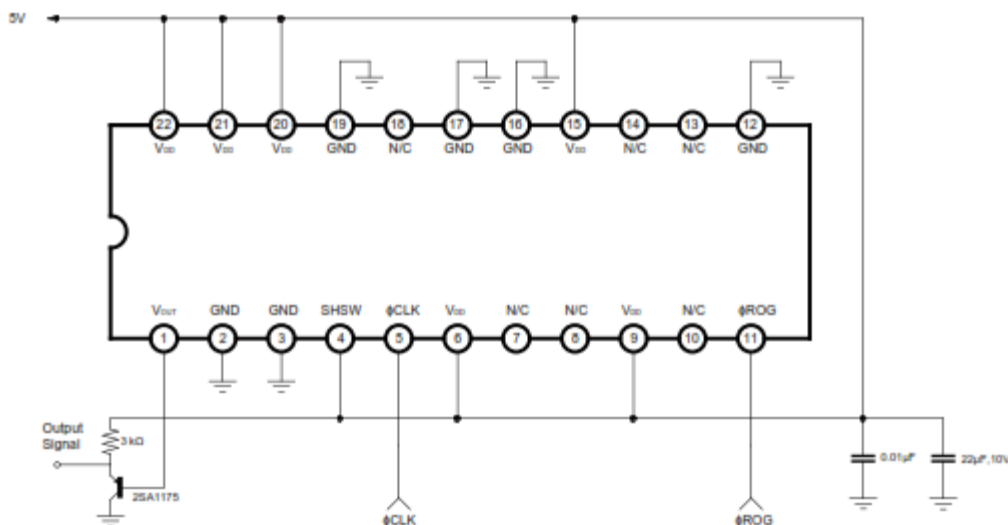
The ITR-511 is designed to provide a highly linear output over a voltage range similar to that in the ILX-511B. Above that range, the ITR-511B slowly approaches saturation to allow extra dynamic range. In saturation, the ITR-511 does not invert, maintaining a fixed level even with very high levels of overexposure.

In the event that the extra dynamic range is to be used for calculation the user may desire to linearize this section of the curve. This is possible with a single digital table because the shape of the curve is consistent from pixel to pixel and from device to device. However, correction tables must always be based on an accurate and stable zero reference.



Application Circuit

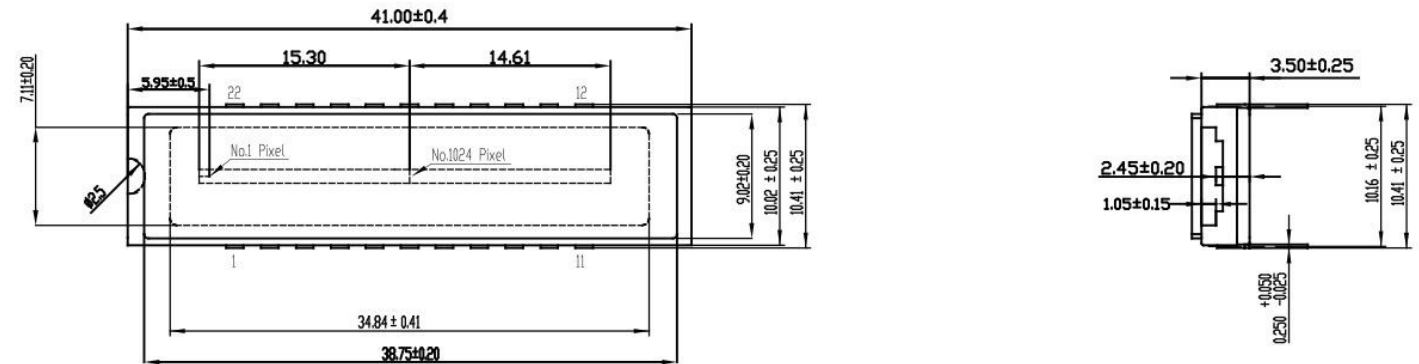
Operating the ITR-511 requires only providing power and the ROG and CLK signals, taking care to assure the N/C pins are not connected and GND pins are properly grounded. If S&H operation is desired, the SHSW pin is connected to ground. In the S&H mode, the ITR-511 utilizes correlated double sampling (CDS) for noise reduction.



ITR-511 2048-Pixel CMOS Line Sensor

Product Brief

Package Outline



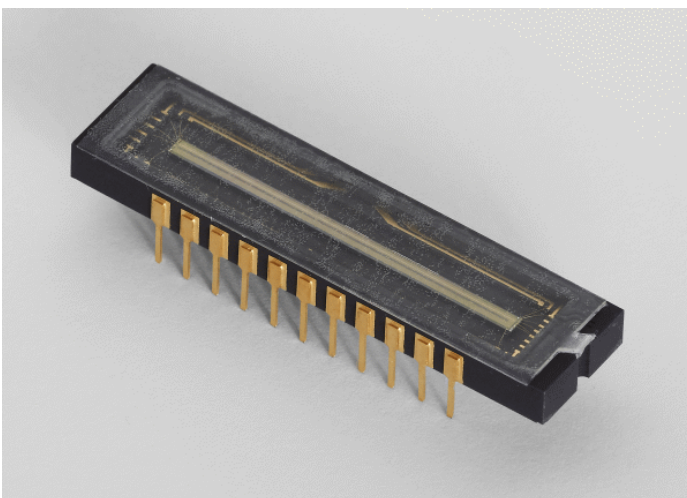
Notes:

- 1 - All dimensions are in mm.
- 2 - The No. 1 pixel is 5.95 ± 0.05 mm from package end
- 3 - The No. 1024 pixel is aligned with the center of the package
- 4 - The sensor surfaced is 2.54 ± 0.4 mm from the package rear
- 5 - The index of refraction of the window is 1.5
- 6 - The package is black alumina
- 7 - The pins are gold-plated iron-nickel alloy 42.

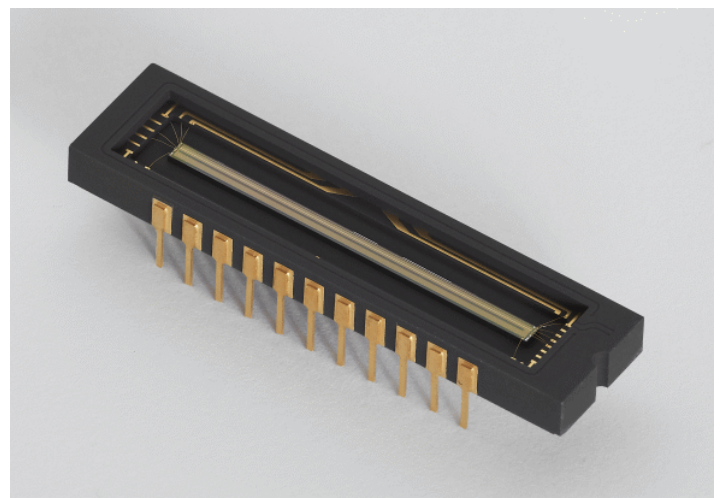
Temporary Window Devices

For applications requiring detection of wavelengths shorter than are passed by the glass window, sensors with removable temporary windows are available. The temporary window may be removed by pulling on the small tab shown in the image below. This should only be done in a static-controlled, dust-free environment to avoid damage to the sensor die. Do not

remove the window until processing is ready to start. **When the temporary window is removed, the device warranty ends.** Care must be taken if a phosphor or fiber optic is to be applied to the die so that the bond wires at the ends of the die are not damaged. Modifications to the sensors should only be undertaken by those with relevant experience.



ITR-511-TW with temporary window in place



ITR-511-TW with temporary window removed

Significant ITR-511 Variances from the Sony ILX511B

While the ITR-511 will operate properly when inserted in most sockets intended for the Sony ILX-511B, the user should be aware of differences between these devices in configuration and performance. Some are significant, such as the increased sensitivity in the red and near-infrared spectrum of the ITR-511 and the various signal offsets. Others are listed here for completeness in case they require operational changes in certain circuit environments. Changes in optical arrangement should not be necessary.

Pixel Height

The height of the pixel in the ITR-511 is 196 μm , slightly shorter than in the ILX-511B. This is occasioned by a design requirement that the pixel height be an integer multiple of the pixel pitch, which is 14 μm .

Sampling Delay

The nominal delay between the clock transition and stable video output is about 100 ns on the ILX511B while the ITR-511 has a much shorter delay, nominally 37 ns. While the width of the stable part of the video output on the ITR-511 should be sufficient to accommodate this change, some board designs placed the ADC sample position so that the shorter delay causes sampling before the video is stable. In such designs, the sampling position may have to be changed.

Dark Current

The dark current in the ITR511 is higher than in the ILX-511B. This may cause uncorrectable offsets or low dynamic range when longer exposures are used. It is recommended that the integration time be kept to no more than 10 msec to avoid potential effects of accumulating dark current.

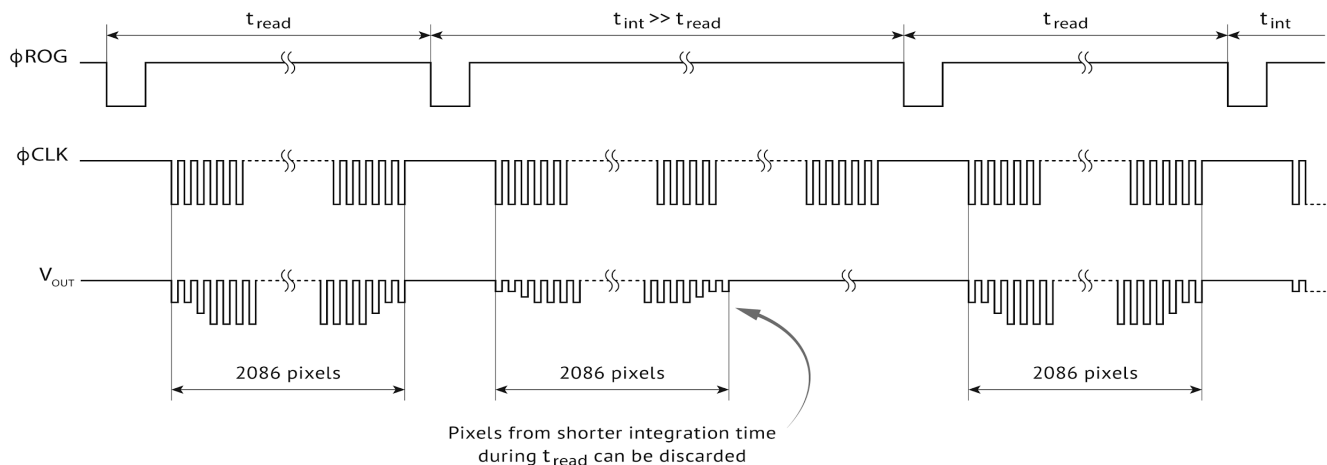
Spectral Response

The ITR-511 has much higher quantum efficiency in the red and near-infrared regions than the ILX-511B. This may extend the useful detection region of the sensor but it will require calibration of any instrument in which it is used. In applications where the infrared must be blocked, care should be taken to assure that the blocking extends beyond the sensitive band of the ITR-511. The response of the ITR511 is uncharacterized below 380 nm but may extend to the 300 nm window cutoff. Applications involving detection or control in the UV bands will require the user to adequately test the ITR-511 in those bands.

Alternate Line Offset Voltage

The ITR-511 uses alternating storage registers to permit readout during integration. It is possible that there may be a small (~ 10 mV) offset between the outputs from these two registers. If the applications software does not use the dark pixel signal to eliminate this offset, it can be bypassed by using data from only every other line.

In the case where the integration time t_{int} is greater than the read-out time, (t_{read}) the ROG timing can be adjusted such that data from alternate lines is read. In the timing diagram below, t_{read} is the minimum time required to acquire data for a given line period from 2086 pixels - for example, about 2.1 msec with a 1 MHz clock. Shorter minimum integration times require faster clocking to permit use of this technique.



ITR-511 2048-Pixel CMOS Line Sensor

Product Brief

Ordering Information

Orders must be placed with the authorized distributor in the country from which the order is placed. Orders sent to Maxwell-Hiqe headquarters from any area with an authorized distributor will be forwarded to the distributor. Orders sent to Imagica Technologies will be sent to Maxwell-Hiqe and forwarded, if appropriate. Quotations are issued only by the authorized distributor.

In some areas, smaller quantities will be sold by authorized dealers. Details can be provided by the distributors in those areas.

SKU	Model	Window
5560002-01	ITR-511-SW	Sealed Glass
5560002-02	ITR-511-TW	Temporary

Other Variations

The ITR-511 can be provided with windows made of other materials or with anti-reflective or other coatings. Contact Maxwell-Hiqe for details

Packaging and Marking

Generally, devices are shipped in antistatic tubes marked with the SKU, Model and quantity. Individual devices may be laser-marked with revision, date and lot codes on the bottom surface. Small quantities packed in antistatic boxes or other suitable containers may be supplied in some areas.

Handling and Storage

The ITR-511 is a CMOS integrated circuit. While it is provided with some protection from static during handling, normal precautions should be taken including grounding of surfaces and operators and avoidance of any static discharge near the device. Devices should be stored in antistatic tubes or boxes in areas where the temperature will not exceed the absolute maximums. Glass windows should be protected from abrasion and devices with temporary windows removed should be protected from unnecessary contact with the sensor die surface. Devices with the temporary windows removed have no protection from static. During soldering, the package temperature should not exceed the stated absolute maximum. These devices are not hermetically sealed.

Restrictions On Use

IMAGICA SEMICONDUCTOR DEVICES ARE NOT DESIGNED OR AUTHORIZED FOR USE IN: (A) SAFETY CRITICAL APPLICATIONS SUCH AS LIFE SUPPORTING APPLICATIONS THAT INCORPORATE, ACTIVE IMPLANTED DEVICES OR SYSTEMS WITH PRODUCT FUNCTIONAL SAFETY REQUIREMENTS; (B) AERONAUTIC APPLICATIONS; (C) AUTOMOTIVE APPLICATIONS OR ENVIRONMENTS; (D) AEROSPACE APPLICATIONS OR (E) ENVIRONMENTS. WHERE IMAGICA SEMICONDUCTOR DEVICES ARE NOT DESIGNED FOR SUCH USE. YOU SHALL USE THE IMAGICA SEMICONDUCTOR DEVICE AT YOUR SOLE RISK, EVEN IF IMAGICA HAS BEEN INFORMED IN WRITING OF SUCH USAGE, UNLESS AN IMAGICA SEMICONDUCTOR DEVICE IS EXPRESSLY DESIGNATED BY IMAGICA AS BEING INTENDED FOR "AUTOMOTIVE, AUTOMOTIVE SAFETY OR MEDICAL" INDUSTRY DOMAINS ACCORDING TO IMAGICA SEMICONDUCTOR DEVICE DESIGN SPECIFICATIONS.

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